# High Voltage Low Power Consumption LDO

#### **MD83XX Series**

#### **CMOS Voltage Regulator**

#### 300mA



MD83XX is a high voltage (up to 40V) low power low dropout voltage regulator (LDO) manufactured in CMOS processes. It can deliver up to 300mA of current while consuming only 1.5uA of quiescent current. It consists of a reference voltage generator, an error amplifier, a current foldback circuit, and a phase compensation circuit plus a driver transistor.

#### ■ FEATURES

- Ultra-low Quiescent Current: 1.5uA
- Maximum Input Voltage: 40V
- Output Voltage Highly Accurate: ±2%
- Maximum Output Current: 300mA
- Dropout Voltage: 4mV@I<sub>OUT</sub>=1mA
- Temperature Stability: ±50ppm/°C
- Protections Circuits: Current Limiter, Foldback, Thermal shutdown
- Output Capacitor: Low ESR Ceramic Capacitor Compatible

#### APPLICATIONS

- Smart wearer
- Long-life battery-powered devices
- Portable mobile devices, such as mobile phones, cameras, and so on
- Wireless communication equipment

## ■ PIN CONFIGURATION (TOP VIEW)



#### Product Selections

Туре	Output Voltage (note 1*)	Current Limit	Accuracy	Package (note 2*)	MARKING (note 3*)
	2.1V	550mA	±2%	SOT89-3	1 8321A
	2.5V	550mA	±2%	SOT89-3	₩ 8325A/ ₩ 8325
	2.7V	550mA	±2%	SOT89-3	🔊 8327A
	2.8V	550mA	A ±2% SOT89-3 🔊 83284		🔊 8328A
	3.0V	550mA	±2%	SOT89-3	🔊 8330A/ 🔊 8330
	3.3V	550mA	±2%	SOT89-3	🔊 8333A/ 🔊 8333
	3.6V	550mA	±2%	SOT89-3	🔊 8336A/ 🔊 8336
	3.8V	550mA	±2%	SOT89-3	🔊 8338A
	4.0V	550mA	±2%	SOT89-3	🔊 8340A/ 🔊 8340
MD83XX	4.1V	550mA	±2%	SOT89-3	🔊 8341A
	4.4V	550mA	±2%	SOT89-3	🔊 8344A/ 🔊 8344
	5.0V	550mA	±2%	SOT89-3	🔊 8350A/ 🔊 8350
	5.3V	550mA	±2%	SOT89-3	🔊 8353A/ 🔊 8353
	5.5V	550mA	±2%	SOT89-3	🔊 8355A/ 🔊 8355
	5.7V	550mA	±2%	SOT89-3	A 8357
	6.0V	550mA	±2%	SOT89-3	🔊 8360A/ 🔊 8360
	10V	550mA	±2%	SOT89-3	🔊 8310A/ 🔊 8310
	12V	550mA	±2%	SOT89-3	₩ 8312A/ ₩ 8312

Notes:

1\* Customer can request to customize the output voltage ranged from 1.2V to 15V if desired voltage is not found in the selections.

 $2^\ast$  Customer can request customization of package choice.

3\* Please pay attention to the MARKING of the product package type.

Absolute Maximum R	Ratings (Unless	s otherwise indicated: Ta	a <b>=25℃)</b>

PARAMETER	SYMBOL	RATINGS		UNITS	
Input Voltage	Vin	-0.3 ~ 45		V	
Output Voltage	V <sub>OUT</sub>	Vss-0.3 ~ VIN+0.3V		V	
Power Dissipation	PD	SOT89-3	1000	mW	
Thermal Resistance	R <sub>θJA</sub>	SOT89-3	100	°C/W	
Operating Ambient Temperature	T <sub>opr</sub>	-40 ~ +85		°C	
Storage Temperature	T <sub>stg</sub>	-40 ~ +125			
ESD Protection	ESD HBM	1500		V	

Note: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device.

## ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	CONDITIONS			MIN.	TYP.	MAX.	UNIT	
Output Voltage*1	V <sub>OUT(S)</sub>	VIN= VOUT(S)+2V, IOUT=10mA			V <sub>OUT(S)</sub> × 0.98	Vout(s)	V <sub>OUT(S)</sub> × 1.02	V	
		V <sub>OUT(S)</sub> =3.3VI <sub>OUT</sub> =1mA			4	8	mV		
Dropout Voltage*2	Vdrop	V <sub>OUT(S)</sub> =3.3V I <sub>OUT</sub> =300mA			1300	1950			
Line Regulation	$\frac{\Delta V_{OUT}}{\Delta V_{IN} \bullet V_{OUT(s)}}$	V <sub>OUT(S)</sub> +2V≤V <sub>IN</sub> ≤40V I <sub>OUT</sub> =1mA			0.01	0.02	%/V		
Load Regulation	$\Delta V_{OUT2}$	$\begin{array}{l lllllllllllllllllllllllllllllllllll$			20	40			
				V <sub>OUT(S)</sub> >5.3V		50	80	mV	
Temperature Stability	$\frac{\Delta V_{OUT}}{\Delta T_a \bullet V_{OUT(s)}}$		Vin = Vout(s)+2V,Iout=10mA -40℃≤Ta≤125℃			±50		<b>ppm/</b> ℃	
GND Current	I <sub>GND</sub>	no load	,	V <sub>OUT(S)</sub> <3.0V	0.8	1.2	2	2	
			3.0≤V <sub>OUT(S)</sub> ≤5.3V		1	1.5	2.5	uA	
			Vout(s)>5.3V		1.5	2.3	3.5		
		I <sub>OUT</sub> =100mA			460				
Input Voltage	VIN			2.2		40	V		
Maximum Output Current	IOUTMAX			300	350				
Current Limit*3	Ішм	$V_{IN} = V_{OUT(S)} + 2V,$ $V_{OUT} = 0.95 \times V_{OUT(S)}$		350	550		mA		
Short Circuit Current <sup>*4</sup>	ISHORT	V <sub>IN</sub> =V <sub>OUT(S)</sub> +2.0V V <sub>OUT</sub> =0V			65				
Power Supply Rejection Ratio		f=10Hz, V <sub>OUT(S)</sub> =3.3V			74				
	PSRR	f=100Hz, V <sub>OUT (S)</sub> =3.3V			63		dB		
		f=1kHz, V <sub>OUT(S)</sub> =3.3V			42				
Over Temperature Protection	OTP	I <sub>OUT</sub> =1mA			170		°C		

MD83XX Series (Unless otherwise indicated: T<sub>a</sub>=25°C)

Notes:

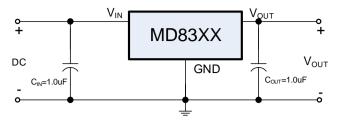
1.  $V_{OUT(S)}$ : Output voltage when  $V_{IN}=V_{OUT}+2V$ ,  $I_{OUT}=1$  mA.

2.  $V_{DROP}=V_{IN1}$  -  $(V_{OUT(S)} x 0.98)$  where  $V_{IN1}$  is the input voltage when  $V_{OUT} = V_{OUT(S)} x 0.98$ .

3. I<sub>LIM</sub>: Output current when  $V_{IN}=V_{OUT(S)}+2V$  and  $V_{OUT}=0.95^*V_{OUT(S)}$ .

4. VOUT pin should be shorted to GND pin, and the impedance between them is less than 0.1 ohm.

## ■ TYPICAL APPLICATIONS

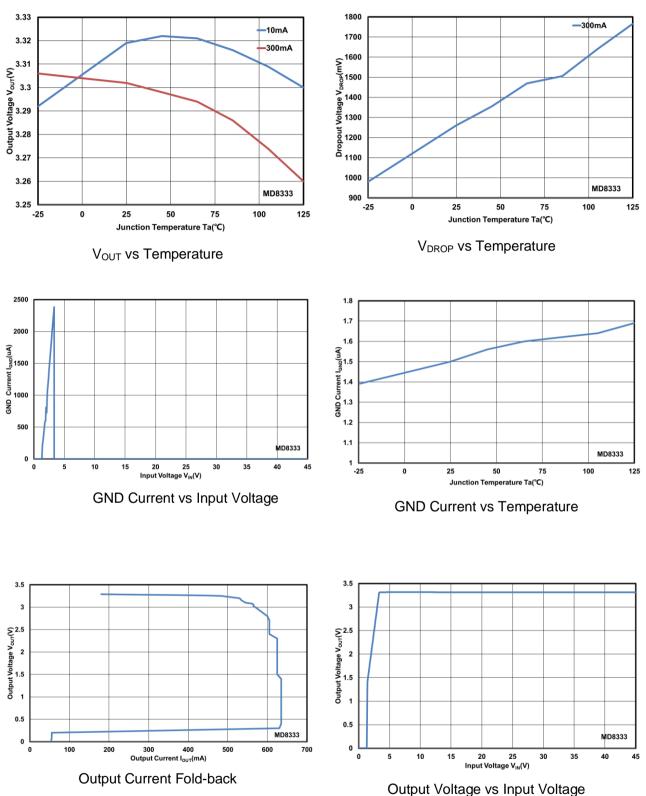


## Notes on Use

Input Capacitor ( $C_{IN}$ ): 1.0µF above Output Capacitor ( $C_{OUT}$ ): 1.0µF above

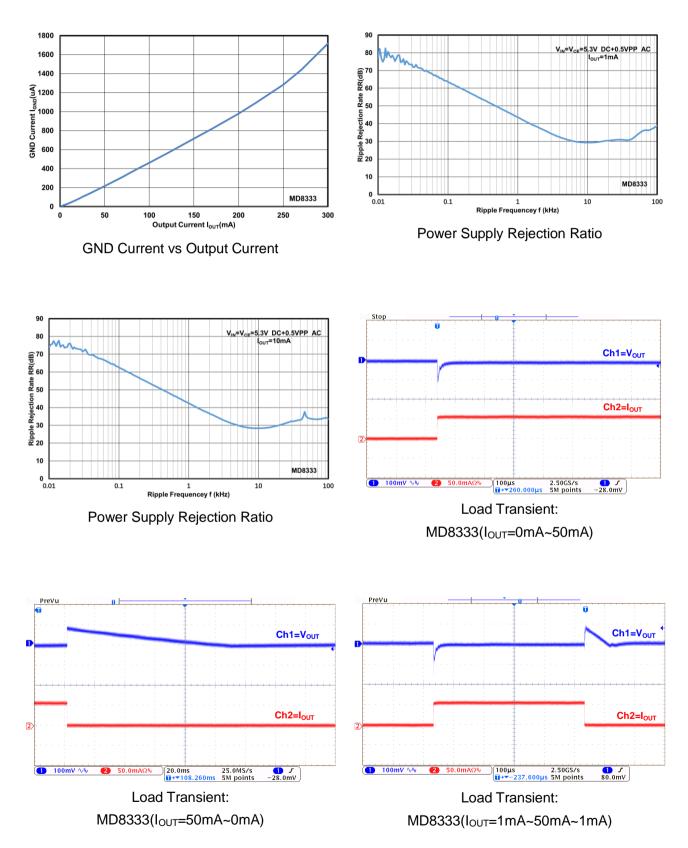
#### ■ TYPICAL PERFORMANCE CHARACTERISTICS

Test Conditions:  $V_{IN}=V_{OUT}+2.0V$ ,  $C_{IN}=1.0\mu F$ ,  $C_{OUT}=1.0\mu F$ ,  $Ta=25^{\circ}C$ , unless otherwise indicated.



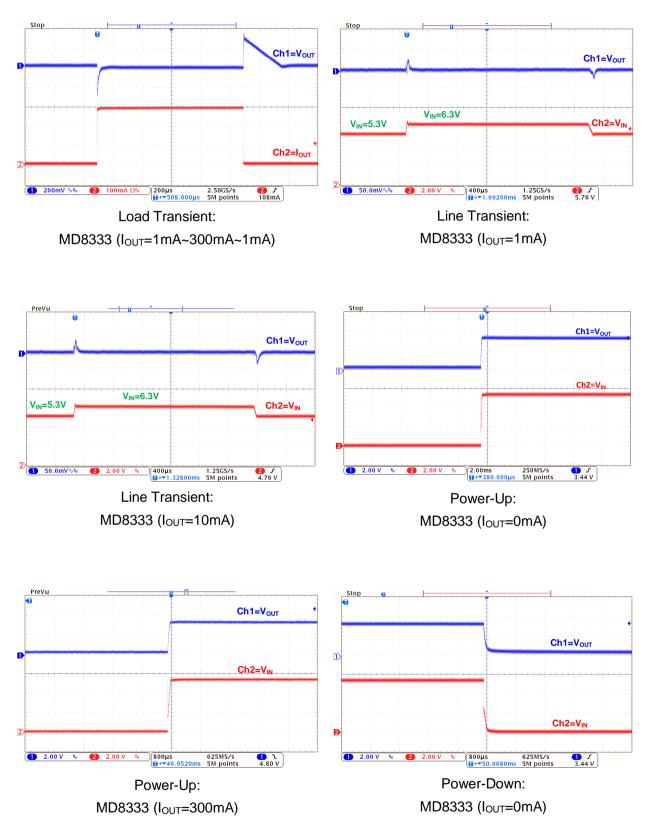
### ■ TYPICAL PERFORMANCE CHARACTERISTICS(CONTINUTED)

Test Conditions:  $V_{IN}=V_{OUT}+2.0V$ ,  $C_{IN}=1.0\mu F$ ,  $C_{OUT}=1.0\mu F$ , unless otherwise indicated.



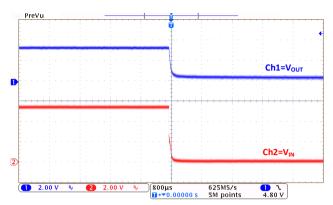
## ■ TYPICAL PERFORMANCE CHARACTERISTICS(CONTINUTED)

Test Conditions: V<sub>IN</sub>=V<sub>OUT</sub>+2.0V, C<sub>IN</sub>=1.0 $\mu$ F, C<sub>OUT</sub>=1.0 $\mu$ F, Ta=25 $^{\circ}$ C, unless otherwise indicated.



#### ■ TYPICAL PERFORMANCE CHARACTERISTICS(CONTINUTED)

Test Conditions: V\_IN=V\_OUT+2.0V, C\_IN=1.0 \mu F, C\_OUT=1.0 \mu F, Ta=25  $^\circ C$  , unless otherwise indicated.

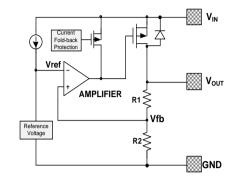


Power-Down: MD8333 (I<sub>OUT</sub>=300mA)

#### OPERATIONAL EXPLANATION

#### 1. Output voltage control

The voltage divided by resistors R1 and R2 is compared with the internal reference voltage by the error amplifier. The amplifier output then drives the P-channel MOSFET connected to the  $V_{OUT}$  pin. The output voltage at the  $V_{OUT}$  pin is regulated by this negative feedback system. The current limit circuit and short protect circuit operate in relation to output current level.



2. Pass transistor

The pass transistor with low turn-on resistance used in MD83XX is a P-channel MOSFET. If the potential on  $V_{OUT}$  pin is higher than VIN, it is possible that IC will be destroyed due to reverse current which is caused by parasitic diodes between  $V_{IN}$  and  $V_{OUT}$ . Therefore, the  $V_{OUT}$  pin potential exceeds  $V_{IN}$ +0.3V is not allowed.

3. Current foldback and over temperature protection

The MD83XX series includes a combination of a fixed current limiter circuit and a foldback circuit, which aid the operations of the current limiter and circuit protection. When the load current reaches the current limit level, the fixed current limiter circuit operates and output voltage drops. As a result of this drop in output voltage, the foldback circuit operates, output voltage drops further and output current decreases. This design can prevent the chip be damaged due to over temperature, moreover, the heat dissipation is limited by the package type.

Special attention should be paid to that the product of the dropout voltage on the chip and the output current must be smaller than the heat dissipation. If power consumption on the chip is more than the heat dissipation, OTP will protect the chip from damaging due to over temperature.

#### ■ Notes:

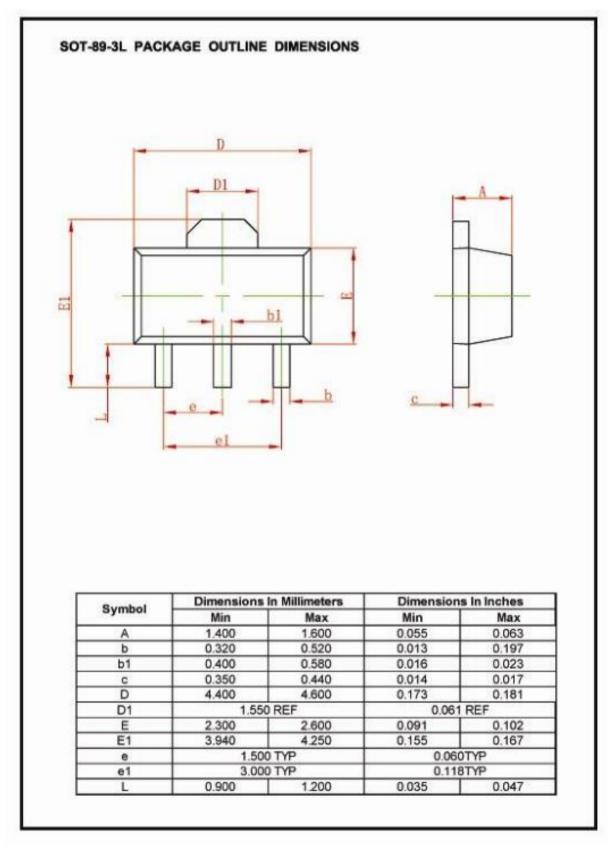
1. The input and output capacitors should be placed as close as possible to the IC.

2. If the impedance of the power supply is high, which is caused by forgetting installing input capacitor or installing too small value capacitor, the oscillation may occur.

3. Pay attention to the operation conditions of input and output voltage and load current, such that the power consumption in the IC should not exceed the allowable power consumption of the package even though the chip has short circuit protection.

4. IC has a built-in anti-static protection (ESD) circuit, but please do not add excessive stress to the IC.

PACKAGING INFORMATION



For the newest datasheet, please see the website: Version V1.6: 20220322 www.md-ic.com.cn